## Low V<sub>CE(sat)</sub> Transistor, NPN, 40 V, 2.0 A

ON Semiconductor's  $e^2$ PowerEdge family of low V<sub>CE(sat)</sub> transistors are miniature surface mount devices featuring ultra low saturation voltage (V<sub>CE(sat)</sub>) and high current gain capability. These are designed for use in low voltage, high speed switching applications where affordable efficient energy control is important.

Typical applications are DC–DC converters and power management in portable and battery powered products such as cellular and cordless phones, PDAs, computers, printers, digital cameras and MP3 players. Other applications are low voltage motor controls in mass storage products such as disc drives and tape drives. In the automotive industry they can be used in air bag deployment and in the instrument cluster. The high current gain allows e<sup>2</sup>PowerEdge devices to be driven directly from PMU's control outputs, and the Linear Gain (Beta) makes them ideal components in analog amplifiers.

#### Features

- NSV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC–Q101 Qualified and PPAP Capable
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant



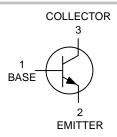
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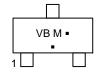
# $\begin{array}{l} \mbox{40 VOLTS, 2.0 AMPS} \\ \mbox{NPN LOW } V_{CE(sat)} \mbox{TRANSISTOR} \\ \mbox{EQUIVALENT } R_{DS(on)} \mbox{44 } m\Omega \end{array}$



SOT-23 (TO-236) CASE 318 STYLE 6



#### MARKING DIAGRAM



VB = Specific Device Code\*

M = Date Code\*

= Pb–Free Package

(Note: Microdot may be in either location)

\*Specific Device Code, Date Code or overbar orientation and/or location may vary depending upon manufacturing location. This is a representation only and actual devices may not match this drawing exactly.

#### **ORDERING INFORMATION**

Device	Package	Shipping <sup>†</sup>
NSS40201LT1G	SOT-23 (Pb-Free)	3,000 / Tape & Reel
NSV40201LT1G	SOT-23 (Pb-Free)	3,000 / Tape & Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

#### **MAXIMUM RATINGS** (T<sub>A</sub> = 25°C)

Rating	Symbol	Max	Unit
Collector-Emitter Voltage	V <sub>CEO</sub>	40	Vdc
Collector-Base Voltage	V <sub>CBO</sub>	40	Vdc
Emitter-Base Voltage	V <sub>EBO</sub>	6.0	Vdc
Collector Current – Continuous	Ι <sub>C</sub>	2.0	А
Collector Current – Peak	I <sub>CM</sub>	6.0	А
Electrostatic Discharge	ESD	HBM Class 3B MM Class C	

#### THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Total Device Dissipation $T_A = 25^{\circ}C$ Derate above $25^{\circ}C$	P <sub>D</sub> (Note 1)	460 3.7	mW mW/°C
Thermal Resistance, Junction-to-Ambient	R <sub>0JA</sub> (Note 1)	270	°C/W
Total Device Dissipation $T_A = 25^{\circ}C$ Derate above 25°C	P <sub>D</sub> (Note 2)	540 4.3	mW mW/°C
Thermal Resistance, Junction-to-Ambient	R <sub>0JA</sub> (Note 2)	230	°C/W
Junction and Storage Temperature Range	T <sub>J</sub> , T <sub>stg</sub>	-55 to +150	°C

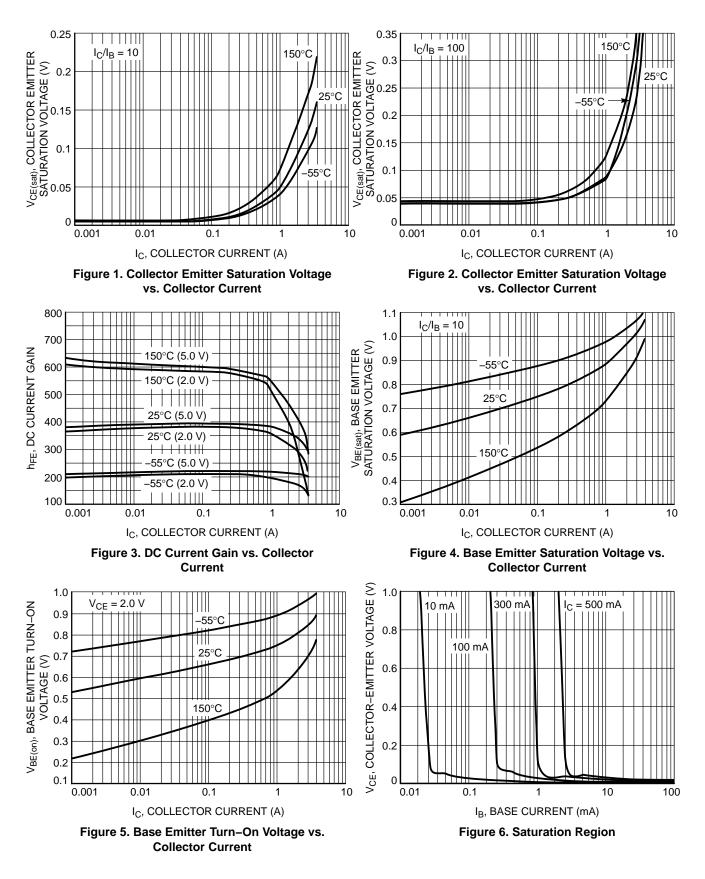
Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected. 1. FR-4 @ 100 mm<sup>2</sup>, 1 oz. copper traces. 2. FR-4 @ 500 mm<sup>2</sup>, 1 oz. copper traces.

#### **ELECTRICAL CHARACTERISTICS** ( $T_A = 25^{\circ}C$ unless otherwise noted)

Characteristic	Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS					
Collector – Emitter Breakdown Voltage $(I_C = 10 \text{ mAdc}, I_B = 0)$	V <sub>(BR)CEO</sub>	40	-	_	Vdc
Collector – Base Breakdown Voltage $(I_{C} = 0.1 \text{ mAdc}, I_{E} = 0)$	V <sub>(BR)CBO</sub>	40	_	_	Vdc
Emitter – Base Breakdown Voltage $(I_E = 0.1 \text{ mAdc}, I_C = 0)$	V <sub>(BR)EBO</sub>	6.0	_	_	Vdc
Collector Cutoff Current ( $V_{CB} = 40 \text{ Vdc}, I_E = 0$ )	I <sub>СВО</sub>	_	_	0.1	μAdc
Emitter Cutoff Current (V <sub>EB</sub> = 6.0 Vdc)	I <sub>EBO</sub>	_	_	0.1	μAdc
ON CHARACTERISTICS			•		
	h <sub>FE</sub>	200 200 180 180	- 370 - -	- - - -	
Collector – Emitter Saturation Voltage (Note 3) ( $I_C = 0.1 A$ , $I_B = 0.010 A$ ) ( $I_C = 1.0 A$ , $I_B = 0.100 A$ ) ( $I_C = 1.0 A$ , $I_B = 0.010 A$ ) ( $I_C = 2.0 A$ , $I_B = 0.200 A$ )	V <sub>CE(sat)</sub>	- - - -	0.006 0.044 0.085 0.082	0.011 0.060 0.115 0.115	V
Base – Emitter Saturation Voltage (Note 3) ( $I_C = 1.0 \text{ A}, I_B = 10 \text{ mA}$ )	V <sub>BE(sat)</sub>	_	0.760	0.900	V
Base – Emitter Turn–on Voltage (Note 3) ( $I_C = 1.0 \text{ A}, V_{CE} = 2.0 \text{ V}$ )	V <sub>BE(on)</sub>	-	0.760	0.900	V
Cutoff Frequency ( $I_C = 100 \text{ mA}$ , $V_{CE} = 5.0 \text{ V}$ , f = 100 MHz)	f <sub>T</sub>	150	_	_	MHz
Input Capacitance ( $V_{EB} = 0.5 V$ , f = 1.0 MHz)	Cibo	_	-	450	pF
Output Capacitance (V <sub>CB</sub> = 3.0 V, f = 1.0 MHz)	Cobo	_	-	45	pF
SWITCHING CHARACTERISTICS	· · ·		•		
Delay (V <sub>CC</sub> = 30 V, $I_C$ = 750 mA, $I_{B1}$ = 15 mA)	t <sub>d</sub>	-	-	100	ns
Rise ( $V_{CC}$ = 30 V, $I_{C}$ = 750 mA, $I_{B1}$ = 15 mA)	t <sub>r</sub>	-	-	100	ns
Storage ( $V_{CC}$ = 30 V, $I_{C}$ = 750 mA, $I_{B1}$ = 15 mA)	t <sub>s</sub>	_	-	750	ns
Fall (V <sub>CC</sub> = 30 V, I <sub>C</sub> = 750 mA, I <sub>B1</sub> = 15 mA)	t <sub>f</sub>	-	-	110	ns

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.
Pulsed Condition: Pulse Width = 300 msec, Duty Cycle ≤ 2%.

#### **TYPICAL CHARACTERISTICS**



#### **TYPICAL CHARACTERISTICS**

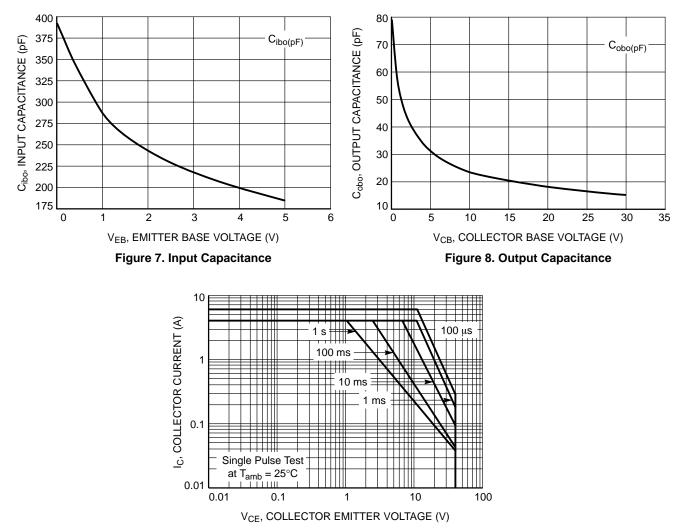


Figure 9. Safe Operating Area

#### **MECHANICAL CASE OUTLINE** PACKAGE DIMENSIONS

D

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TOP VIEW

SIDE VIEW

Нe

DETAIL A

-3X b

# DUSem



SCALE 4:1

Α A1SOT-23 (TO-236) **CASE 318 ISSUE AT** 

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DETAIL A

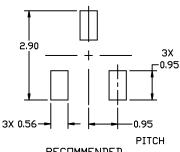
END VIEW

DATE 01 MAR 2023

NDTES:

- 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M,1994.
- CONTROLLING DIMENSION: MILLIMETERS 2.
- MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS DF THE BASE MATERIAL. З.
- DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS. 4.

	MILLIM	ILLIMETERS INCHES				
DIM	MIN.	NDM.	MAX.	MIN.	NDM.	MAX.
Α	0.89	1.00	1.11	0.035	0.039	0.044
A1	0.01	0.06	0.10	0.000	0.002	0.004
b	0.37	0.44	0.50	0.015	0.017	0.020
с	0.08	0.14	0.20	0.003	0.006	0.008
D	2.80	2.90	3.04	0.110	0.114	0.120
E	1.20	1.30	1.40	0.047	0.051	0.055
e	1.78	1.90	2.04	0.070	0.075	0.080
L	0.30	0.43	0.55	0.012	0.017	0.022
L1	0.35	0.54	0.69	0.014	0.021	0.027
Η <sub>E</sub>	2.10	2.40	2.64	0.083	0.094	0.104
Т	0*		10*	0*		10*



RECOMMENDED MOUNTING FOOTPRINT

For additional information on our Pb-Free strategy and soldering details, please download the DN Semiconductor Soldering and Mounting Techniques Reference Manual, SDLDERRM/D. \*

GENERIC **MARKING DIAGRAM\*** 



XXX = Specific Device Code

М = Date Code

= Pb-Free Package .

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

#### **STYLES ON PAGE 2**

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## MECHANICAL CASE OUTLINE

PACKAGE DIMENSIONS

# onsemi

#### SOT-23 (TO-236) CASE 318 ISSUE AT

#### DATE 01 MAR 2023

STYLE 1 THRU 5: CANCELLED	STYLE 6: PIN 1. BASE 2. EMITTER 3. COLLECTOR	STYLE 7: PIN 1. EMITTER 2. BASE 3. COLLECTOR	STYLE 8: PIN 1. ANODE 2. NO CONNECTION 3. CATHODE		
STYLE 9:	STYLE 10:	STYLE 11:	STYLE 12:	STYLE 13:	STYLE 14:
PIN 1. ANODE	PIN 1. DRAIN	PIN 1. ANODE	PIN 1. CATHODE	PIN 1. SOURCE	PIN 1. CATHODE
2. ANODE	2. SOURCE	2. CATHODE	2. CATHODE	2. DRAIN	2. GATE
3. CATHODE	3. GATE	3. CATHODE-ANODE	3. ANODE	3. GATE	3. ANODE
STYLE 15:	STYLE 16:	STYLE 17:	STYLE 18:	STYLE 19:	STYLE 20:
PIN 1. GATE	PIN 1. ANODE	PIN 1. NO CONNECTION	PIN 1. NO CONNECTION	PIN 1. CATHODE	PIN 1. CATHODE
2. CATHODE	2. CATHODE	2. ANODE	2. CATHODE	2. ANODE	2. ANODE
3. ANODE	3. CATHODE	3. CATHODE	3. ANODE	3. CATHODE-ANODE	3. GATE
STYLE 21:	STYLE 22:	STYLE 23:	STYLE 24:	STYLE 25:	STYLE 26:
PIN 1. GATE	PIN 1. RETURN	PIN 1. ANODE	PIN 1. GATE	PIN 1. ANODE	PIN 1. CATHODE
2. SOURCE	2. OUTPUT	2. ANODE	2. DRAIN	2. CATHODE	2. ANODE
3. DRAIN	3. INPUT	3. CATHODE	3. SOURCE	3. GATE	3. NO CONNECTION
STYLE 27: PIN 1. CATHODE 2. CATHODE 3. CATHODE	STYLE 28: PIN 1. ANODE 2. ANODE 3. ANODE				

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